SWITCHMODE TM

NPN Bipolar Power Transistor For Switching Power Supply Applications

The BUL147 have an applications specific state-of-the-art die designed for use in electric fluorescent lamp ballasts to 180 Watts and in Switchmode Power supplies for all types of electronic equipment.

Features

- Improved Efficiency Due to Low Base Drive Requirements:
 - High and Flat DC Current Gain
 - ♦ Fast Switching
 - No Coil Required in Base Circuit for Turn–Off (No Current Tail)
- Parametric Distributions are Tight and Consistent Lot-to-Lot
- Two Package Choices: Standard TO-220 or Isolated TO-220
- Pb-Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Sustaining Voltage	V _{CEO}	400	Vdc	
Collector-Base Breakdown Voltage	V _{CES}	700	Vdc	
Emitter-Base Voltage	V _{EBO}	9.0	Vdc	
Collector Current – Continuous – Peak (Note 1)	I _C I _{CM}	8.0 16	Adc	
Base Current – Continuous – Peak (Note 1)	I _B I _{BM}	4.0 8.0	Adc	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	125 1.0	W/°C	
Operating and Storage Temperature	Tj, T _{stg}	-65 to 150	°C	

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	1.0	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

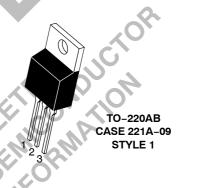
1. Pulse Test: Pulse Width = 5 ms, Duty Cycle \leq 10%.



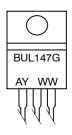
ON Semiconductor®

http://onsemi.com

POWER TRANSISTOR 8.0 AMPERES, 700 VOLTS, 45 AND 125 WATTS



MARKING DIAGRAM



BUL147	= Device Code
Α	= Assembly Location
Y	= Year
WW	= Work Week
G	= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
BUL147	TO-220	50 Units / Rail
BUL147G	TO-220 (Pb-Free)	50 Units / Rail

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

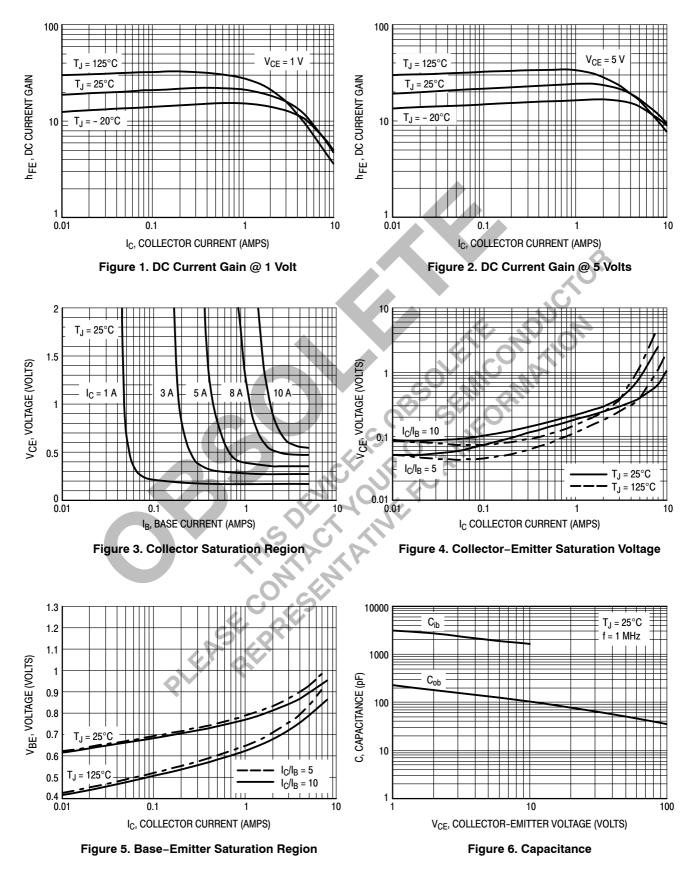
Characteristic			Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Collector–Emitter Sustaining Vol $(I_C = 100 \text{ mA}, L = 25 \text{ mH})$	tage		V _{CEO(sus)}	400	_	_	Vdc
Collector Cutoff Current (V_{CE} = Rated V_{CEO} , I_B = 0)			I _{CEO}	_	_	100	μAdc
Collector Cutoff Current (V_{CE} = Rated V_{CES} , V_{EB} = 0) (V_{CE} :	= 500 V, V _{EB} = 0)	(T _C = 125°C) (T _C = 125°C)	I _{CES}	- - -	- -	100 500 100	μAdc
Emitter Cutoff Current ($V_{EB} = 9.0 \text{ Vdc}, I_C = 0$)			I _{EBO}	_	_	100	μAdc
ON CHARACTERISTICS							
$\begin{array}{l} \text{Base-Emitter Saturation Voltage} \\ (I_{C} = 2.0 \text{ Adc}, I_{B} = 0.2 \text{ Adc}) \\ (I_{C} = 4.5 \text{ Adc}, I_{B} = 0.9 \text{ Adc}) \end{array}$)		V _{BE(sat)}	-	0.82 0.92	1.1 1.25	Vdc
Collector-Emitter Saturation Volt ($I_C = 2.0 \text{ Adc}, I_B = 0.2 \text{ Adc}$)	tage	(T _C = 125°C)	V _{CE(sat)}	-	0.25 0.3	0.5 0.5	Vdc
$(I_{C} = 4.5 \text{ Adc}, I_{B} = 0.9 \text{ Adc})$		(T _C = 125°C)			0.35 0.35	0.7	
(I _C = 2.0 Adc,	, V _{CE} = 1.0 Vdc)	$(T_{C} = 125^{\circ}C)$ $(T_{C} = 125^{\circ}C)$ $T_{C} = 25^{\circ}C \text{ to } 125^{\circ}C)$	h _{FE}	14 8.0 7.0 10 10	30 12 11 18 20	34 - - - -	_
DYNAMIC CHARACTERISTICS			07 3				ļ
Current Gain Bandwidth ($I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f$	= 1.0 MHz)	JCF JP	fτ	-	14	-	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 I	MHz)	\$ 4°	C _{ob}	-	100	175	pF
Input Capacitance (V _{EB} = 8.0 V)	JIS.	CAN	C _{ib}	_	1750	2500	pF
	(I _C = 2.0 Adc I _{B1} = 200 mAdc	μs (T _C = 125°C)		-	3.0 5.5	-	
Determined 1.0 μs and 3.0 μs respectively after	$V_{\rm CC} = 300 \text{ V}$ 3.0	μ s (T _C = 125°C)	V	-	0.8 1.4	-	v
rising I _{B1} reaches 90% of final I _{B1} (see Figure 18)	(I _C = 5.0 Adc I _{B1} = 0.9 Adc	μs (T _C = 125°C)	V _{CE(dsat)}	-	3.3 8.5	-	v
	$V_{\rm CC} = 300 \text{ V}$ 3.0	μs (T _C = 125°C)		-	0.4 1.0	-	

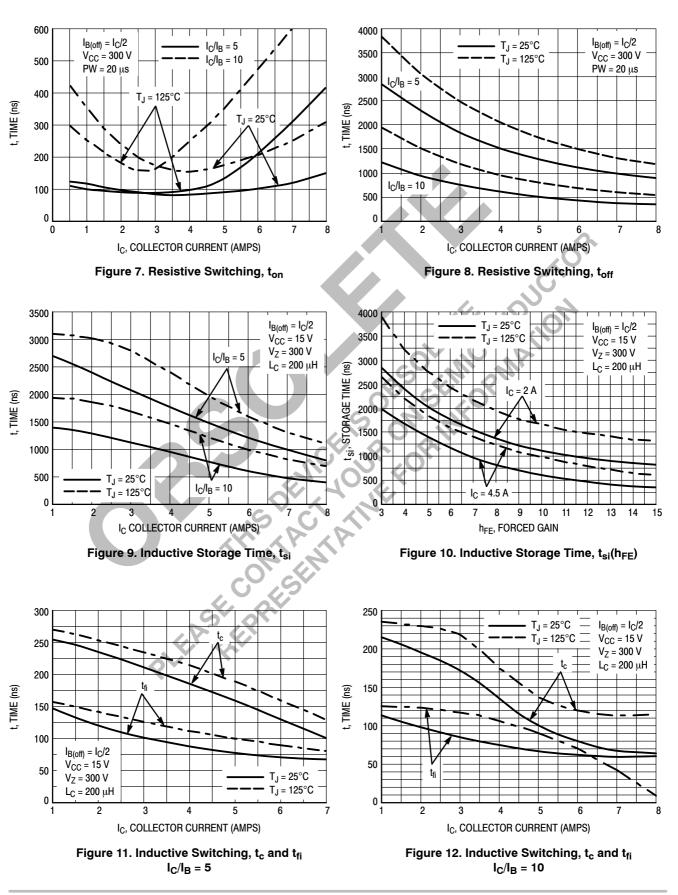
	Characteristic		Symbol	Min	Тур	Max	Unit	
SWITCHING CHARACTERISTICS: Resistive Load (D.C. ≤ 10%, Pulse Width = 20 μs)								
Turn-On Time	$(I_{C} = 2.0 \text{ Adc}, I_{B1} = 0.2 \text{ Adc})$ $I_{B2} = 1.0 \text{ Adc}, V_{CC} = 300 \text{ V})$	(T _C = 125°C)	t _{on}		200 190	350 -	ns	
Turn-Off Time		(T _C = 125°C)	t _{off}		1.0 1.6	2.5 _	μs	
Turn-On Time	$(I_{C} = 4.5 \text{ Adc}, I_{B1} = 0.9 \text{ Adc})$ $I_{B1} = 2.25 \text{ Adc}, V_{CC} = 300 \text{ V})$	(T _C = 125°C)	t _{on}		85 100	150 -	ns	
Turn–Off Time	_	(T _C = 125°C)	t _{off}	-	1.5 2.0	2.5 _	μs	

SWITCHING CHARACTERISTICS: Inductive Load (V_{clamp} = 300 V, V_{CC} = 15 V, L = 200 μ H)

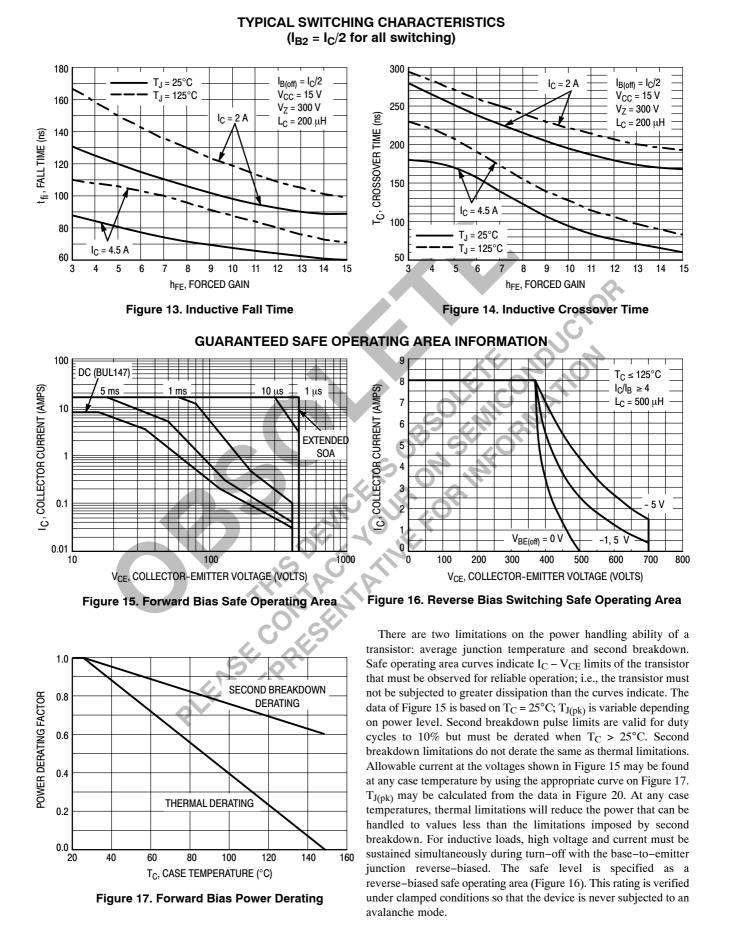
Fall Time	(I _C = 2.0 Adc, I _{B1} = 0.2 Adc I _{B2} = 1.0 Adc)	(T _C = 125°C)	t _{fi}	-	100 120	180 -	ns
Storage Time		(T _C = 125°C)	t _{si}	-	1.3 1.9	2.5	μs
Crossover Time		(T _C = 125°C)	t _c		210 230	350 -	ns
Fall Time	$(I_{C} = 4.5 \text{ Adc}, I_{B1} = 0.9 \text{ Adc} \ I_{B2} = 2.25 \text{ Adc})$	(T _C = 125°C)	t _{fi}	-	80 100	150 -	ns
Storage Time		(T _C = 125°C)	t _{si}	0	1.6 2.1	3.2	μs
Crossover Time		(T _C = 125°C)	tc		170 200	300 -	ns
Fall Time	$(I_{C} = 4.5 \text{ Adc}, I_{B1} = 0.9 \text{ Adc})$ $I_{B2} = 0.9 \text{ Adc})$	(T _C = 125°C)	t _{fi}	60 -	_ 150	180 -	ns
Storage Time		(T _C = 125°C)	t _{si}	2.6 _	_ 4.3	3.8 -	μs
Crossover Time		(T _C = 125°C)	tc		200 330	350 -	ns
C	PLEASE PEPE	ENTAIN					

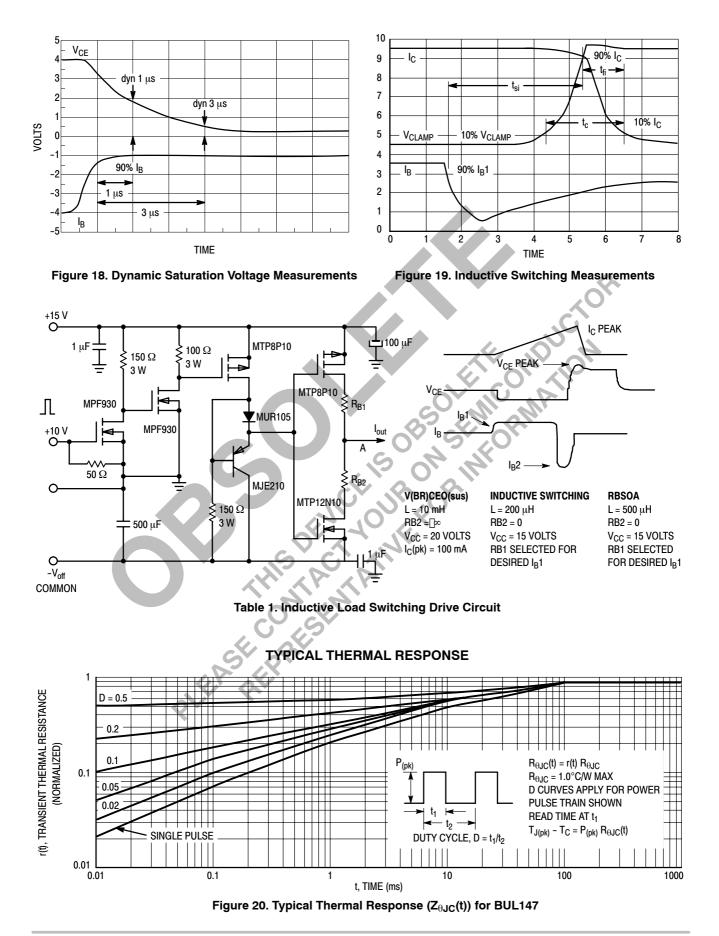
TYPICAL STATIC CHARACTERISTICS





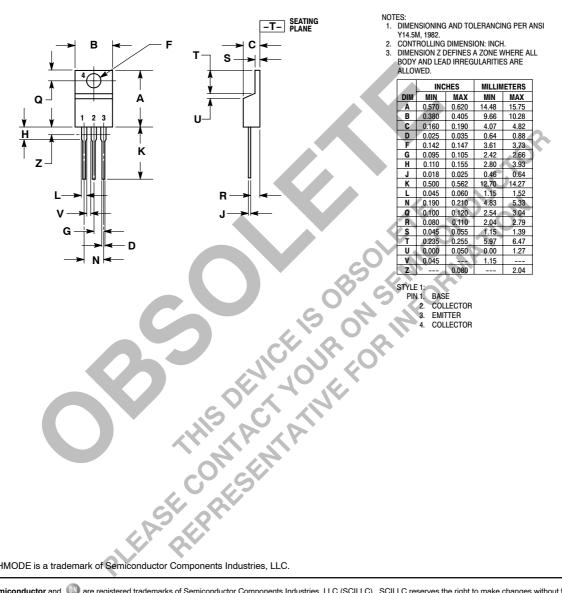
TYPICAL SWITCHING CHARACTERISTICS ($I_{B2} = I_C/2$ for all switching)





PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE AA**



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